

KSC2787

FM/AM RF AMP, MIX, CONV, OSC, IF

- Collector-Emitter Voltage: V_{CEO}=30V
 High Current Gain Bandwidth Product: f_T=300MHz (TYP)
- Low Output Capacitance : Cob=2.0pF (TYP)



1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	30	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	50	mA
P _C	Collector Power Dissipation	250	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{C}=10\mu A, I_{E}=0$	50			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5mA$, $I_B=0$	30			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E}=10\mu A, I_{C}=0$	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =50V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =5V, I_{C} =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =6V, I _C =1mA	40		240	
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =6V, I _C =1mA		0.67	0.75	V
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA		0.08	0.3	V
f _T	Current Gain Bandwidth Product	V _{CE} =6V, I _C =1mA	150	300		MHz
C _{ob}	Output Capacitance	V _{CB} =6V, I _E =0, f=1MHz		2.0	2.5	pF

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

Typical Characteristics

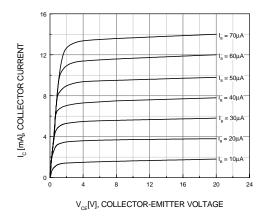


Figure 1. Static Characteristics

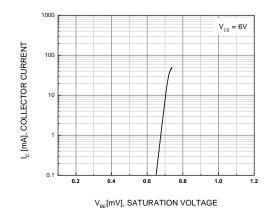


Figure 2. Base-Emitter On Voltage

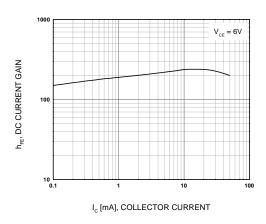


Figure 3. DC Current Gain

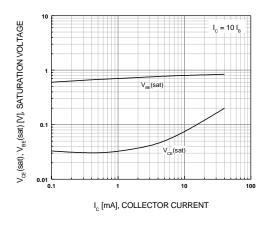
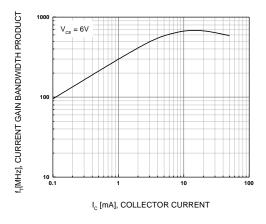


Figure 4. Saturation Voltage





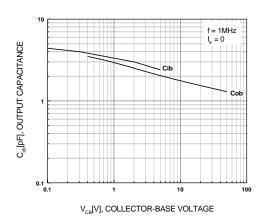
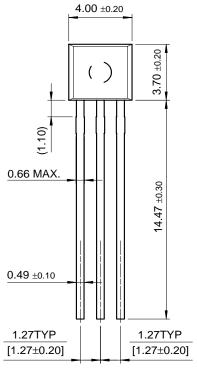


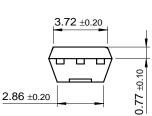
Figure 6. Output Capacitance

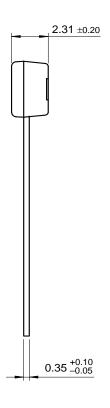
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Package Dimensions

TO-92S







Dimensions in Millimeters

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EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
EnSigna™	I^2C^{TM}	OCX^{TM}	RapidConfigure™	UHC™
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The Power Franchise™		OPTOLOGIC [®]	SILENT SWITCHER®	VCX^{TM}
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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